

	<h2 style="color: red;">RFD16N06LESM9A</h2>
	<p>Hersteller-Teilenummer: RFD16N06LESM9A</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 60V 16A DPAK</p> <hr/> <p>Datenblätter:  RFD16N06LESM9A.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 10100 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	RFD16N06LESM9A
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 60V 16A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	10100 pcs Stock
Hersteller Standard Vorlaufzeit	9 Weeks
detaillierte Beschreibung	N-Channel 60V 16A (Tc) 90W (Tc) Surface Mount TO-
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	TO-252AA
Verlustleistung (max)	90W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	16A (Tc)
Rds On (Max) @ Id, Vgs	47 mOhm @ 16A, 5V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	62nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1350pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	5V
Vgs (Max)	+10V, -8V
Verpackung	Cut Tape (CT)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	RFD16N06LESM9ACT



















































RFD16N06LESM9A ist neu im Original, Suche RFD16N06LESM9A Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie RFD16N06LESM9A AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage RFD16N06LESM9A: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>RFD16N06LESM9A Fairchild/ON Semiconductor MOSFET N-CH 60V 16A DPAK</p>	 <p>RFD20N03SM HAR RFD20N03SM HAR</p>	 <p>RFD16N06L FSC RFD16N06L FSC</p>	 <p>RFD16N06SM9A HAR RFD16N06SM9A HAR</p>
 <p>RFD16N06LESM F RFD16N06LESM F</p>	 <p>RFD16N06 I RFD16N06 I</p>	 <p>RFD21711 RF Digital BOARD 24L01 RF TXRX</p>	 <p>RFD16N05SM9A AMI Semiconductor / ON Semiconductor MOSFET N-CH 50V 16A TO-252AA</p>

heiße Teile

Mehr

 RFD15P06SM	 RFD15P06SM9AS2463	 RFD16N02	 RFD16N02L	 RFD16N02LSM
 RFD16N02LSM9A	 RFD16N03L	 RFD16N03LSM	 RFD16N03LSM9A	 RFD16N05
 RFD16N05	 RFD16N05L	 RFD16N05LSM	 RFD16N05LSM	 RFD16N05LSM-NL
 RFD16N05LSM96S5000	 RFD16N05LSM9A	 RFD16N05LSM9A	 RFD16N05SM	 RFD16N05SM
 RFD16N05SM9A	 RFD16N05SM9A	 RFD16N06	 RFD16N06L	 RFD16N06LESM
 RFD16N06LESM9A	 RFD16N06SM9A	 RFD20N03SM	 RFD20N03SM9A	 RFD3055L
 RFD3055LE	 RFD3055LE	 RFD3055LESM	 RFD3055LESM	 RFD3055LESM9A
 RFD3055LESM9A	 RFD3055LESM9AS2568	 RFD3055RLESM96	 RFD3055RLESM9A	 RFD3055SM
 RFD3055SM	 RFD3055SM9A	 RFD3055SM9A	 RFD4N06LSM	 RFD8P05SM
 RFD8P05SM	 RFD8P05SM9A	 RFD8P06ESM	 RFD8P06ESM9A	 RFD8P06LESM

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